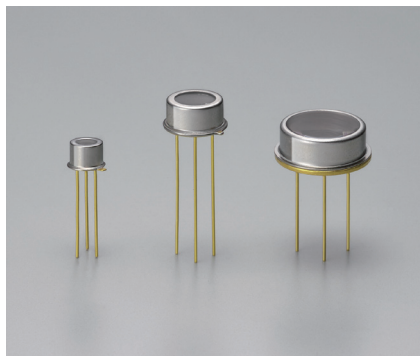


InGaAs PIN photodiodes



G8370-81/-82/-83/-85

Low PDL (Polarization Dependence Loss)

InGaAs PIN photodiodes G8370-81/-82/-83/-85 have low PDL at 1.55 μm , large shunt resistance and very low noise. Hamamatsu provides various types of InGaAs PIN photodiodes with photosensitive areas from $\phi 1$ to $\phi 5$ mm.

Features

- Low PDL
- Low noise, low dark current
- Large photosensitive area
- Various photosensitive area sizes available

Applications

- Laser monitor
- Optical power meter
- Laser diode life test

Structure/Absolute maximum ratings

Type no.	Dimensional outline/ Window material*1	Package	Photosensitive area (mm)	Absolute maximum ratings		
				Reverse voltage V_R max (V)	Operating temperature T_{opr} (°C)	Storage temperature T_{stg} (°C)
G8370-81	(1)/A	TO-18	$\phi 1$	5	-40 to +85	-55 to +125
G8370-82	(2)/A	TO-5	$\phi 2$	2		
G8370-83			$\phi 3$			
G8370-85	(3)/A	TO-8	$\phi 5$	1		

*1: A=Borosilicate glass with anti-reflective coating (optimized for 1.55 μm peak)

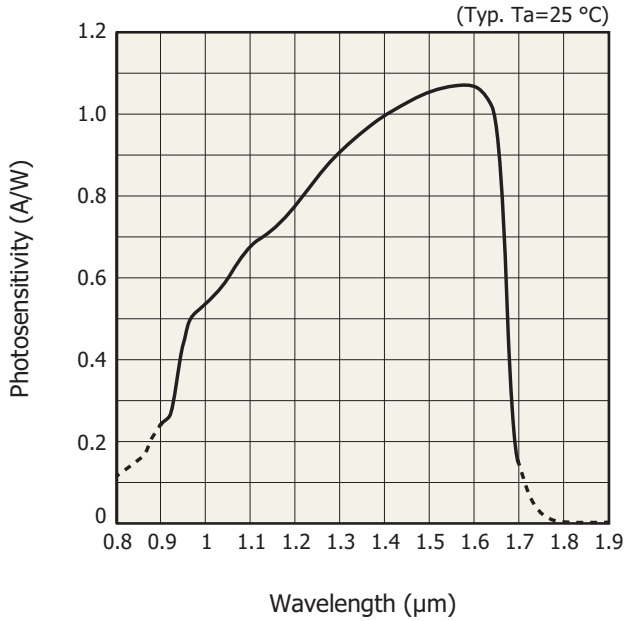
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Typ. $T_a=25$ °C, unless otherwise noted)

Type no.	Spectral response range (μm)	Peak sensitivity wavelength λ_p (μm)	Photosensitivity S				Dark current I_D $V_R=1$ V		Cutoff frequency f_c $V_R=1$ V $R_L=50$ Ω -3 dB (MHz)	Terminal capacitance C_t $V_R=1$ V $f=1$ MHz (pF)	Shunt resistance R_{sh} $V_R=10$ mV (M Ω)	PDL $\lambda=\lambda_p$		D^* $\lambda=\lambda_p$ ($\text{cm}\cdot\text{Hz}^{1/2}/\text{W}$)	NEP $\lambda=\lambda_p$ ($\text{W}/\text{Hz}^{1/2}$)
			1.3 μm		$\lambda=\lambda_p$		Typ. (nA)	Max. (nA)				Typ. (mdB)	Max. (mdB)		
			Min. (A/W)	Typ. (A/W)	Min. (A/W)	Typ. (A/W)									
G8370-81	0.9 to 1.7	1.55	0.8	0.9	0.85	1.1	1	5	35	90	100	5	10	5×10^{12}	2×10^{-14}
G8370-82							5	25	4	550	25				4×10^{-14}
G8370-83							15	75	2	1000	10				6×10^{-14}
G8370-85							25*2	125*2	0.6	3500	3				1×10^{-13}

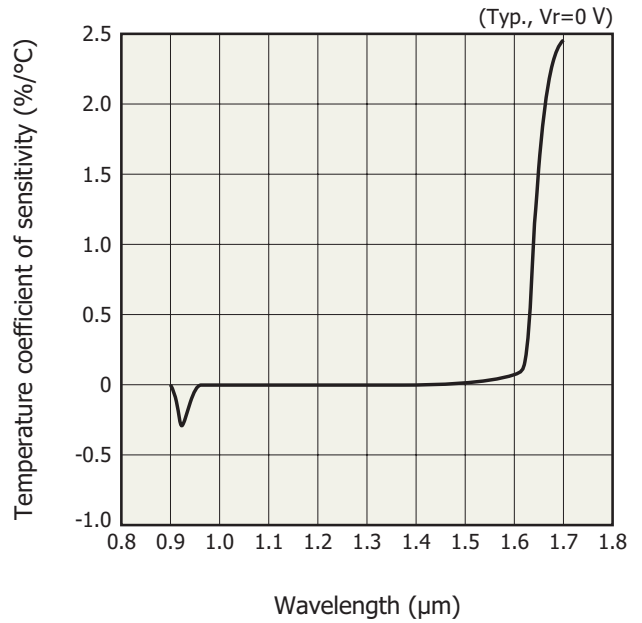
*2: $V_R=0.1$ V

Spectral response



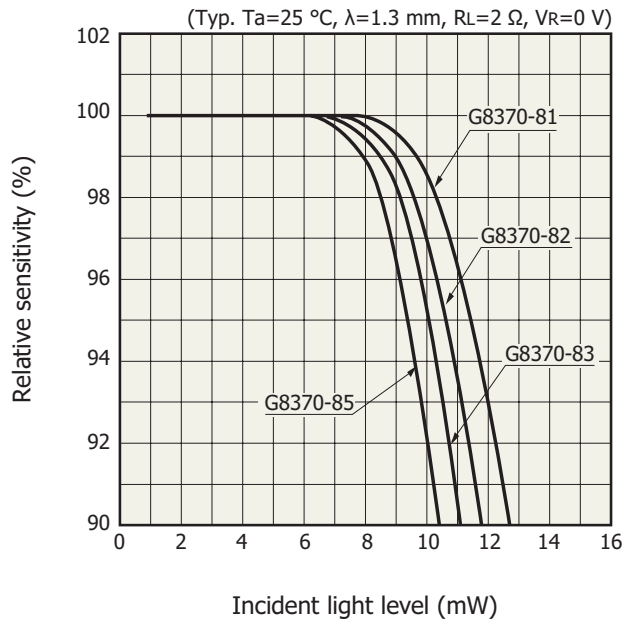
KIRDB0374EA

Photosensitivity temperature characteristics



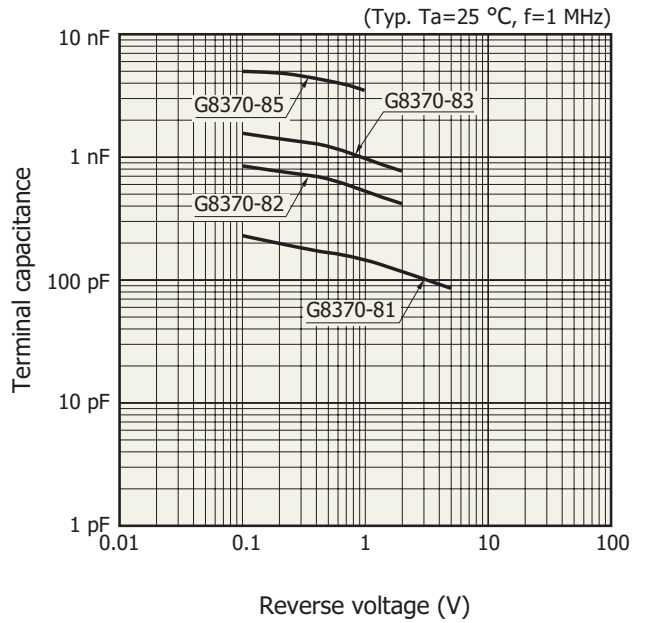
KIRDB0042EB

Photosensitivity linearity



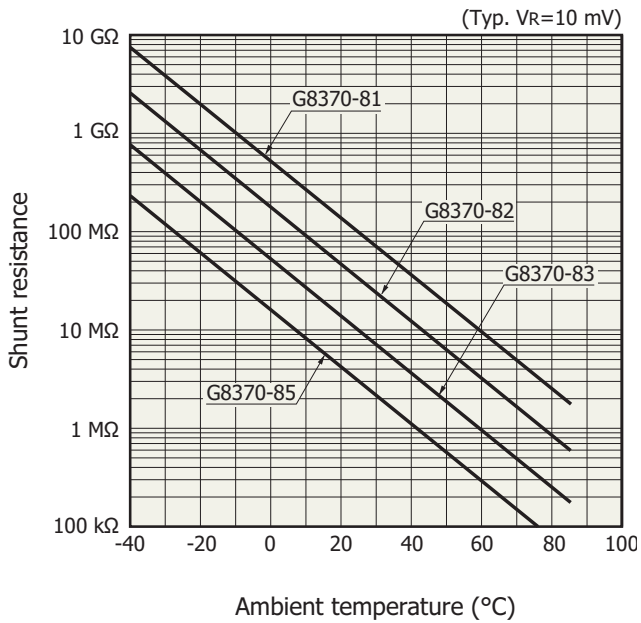
KIRDB0298EA

Terminal capacitance vs. reverse voltage



KIRDB0299EA

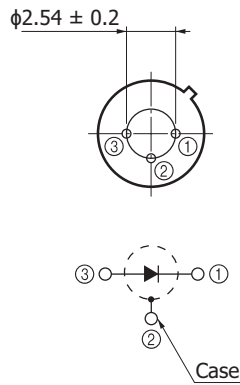
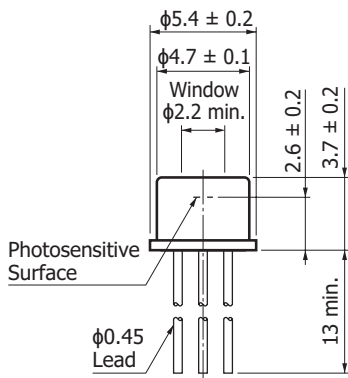
Shunt resistance vs. ambient temperature



KIRD80300EA

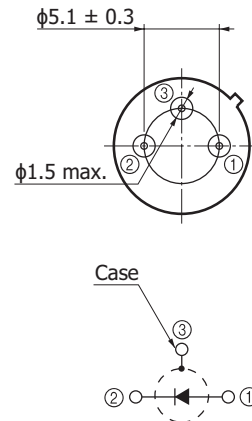
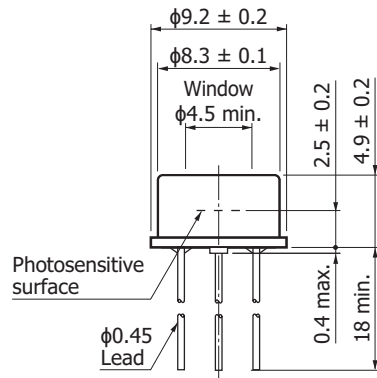
Dimensional outlines (unit: mm)

(1) G8370-81



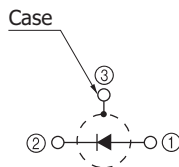
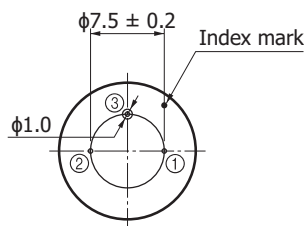
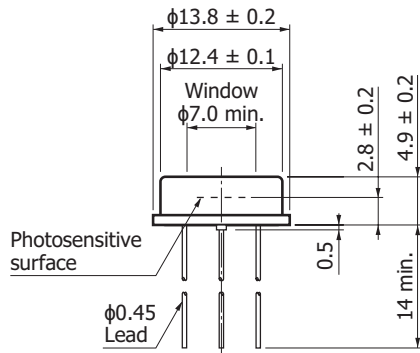
KIRDA0189EB

(2) G8370-82/-83



KIRDA0155EB

(3) G8370-85



KIRDA0052EC

■ Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Disclaimer
- Metal, ceramic, plastic package products
- Compound opto-semiconductors (photosensors, light emitters)

Information described in this material is current as of July, 2020.

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